SMLS128E-OCTOBER 1984-REVISED JANUARY 1993

This Data Sheet is Applicable to All TMS27C128s and TMS27PC128s Symbolized with Code "B" as Described on Page 12.

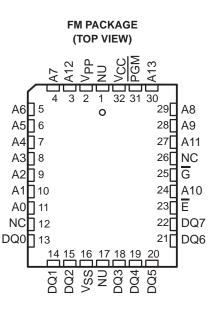
- Organization . . . 16K × 8
- Single 5-V Power Supply
- Pin Compatible With Existing 128K MOS ROMs, PROMs, and EPROMs
- All Inputs/Outputs Fully TTL Compatible
- Max Access/Min Cycle Times <u>V_{CC} ± 10%</u> '27C128-12 120 ns '27C/PC128-15 150 ns '27C/PC128-20 200 ns '27C/PC128-25 250 ns
- Power Saving CMOS Technology
- Very High-Speed SNAP! Pulse Programming
- 3-State Output Buffers
- 400-mV Minimum DC Noise Immunity With Standard TTL Loads
- Latchup Immunity of 250 mA on All Input and Output Lines
- Low Power Dissipation (V_{CC} = 5.25 V)
 Active ... 158 mW Worst Case
 - Standby . . . 1.4 mW Worst Case (CMOS Input Levels)
- PEP4 Version Available With 168-Hour Burn-In and Choices of Operating Temperature Ranges
- 128K EPROM Available With MIL-STD-883C Class B High-Reliability Processing (SMJ27C128)

description

The TMS27C128 series are 131 072-bit, ultraviolet-light erasable, electrically programmable read-only memories.

The TMS27PC128 series are 131 072-bit, one time electrically programmable read-only memories.

J AN	ID N PA	CK/	AGES
(TOP VI	EW))
V _{PP} [$ _1$ \bigcirc	28	Vcc
A12[2	27] PGM
A7[3	26] A13
A6 [4	25] A8
A5 [5	24] A9
A4 [6	23	A11
A3[7	22] G
A2[8	21	<u> </u> A10
A1 [9	20	ΠĒ
AO	10	19	DQ7
DQ0	11	18	DQ6
DQ1	12	17	DQ5
DQ2	13	16	DQ4
GND	14	15	DQ3



	PIN NOMENCLATURE
A0-A13	Address Inputs
E	Chip Enable/Powerdown
G	Output Enable
ND	Ground
NC	No Connection
NU	Make No External Connection
PGM	Program
DQ0-DQ7	Inputs (programming)/Outputs
VCC	5-V Power Supply
VPP	12-13 V Programming Power Supply

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.



Copyright © 1993, Texas Instruments Incorporated

SMLS128E-OCTOBER 1984-REVISED JANUARY 1993

These devices are fabricated using power-saving CMOS technology for high speed and simple interface with MOS and bipolar circuits. All inputs (including program data inputs) can be driven by Series 74 TTL circuits without the use of external pull-up resistors. Each output can drive one Series 74 TTL circuit without external resistors.

The data outputs are three-state for connecting multiple devices to a common bus. The TMS27C128 and the TMS27PC128 are pin compatible with 28-pin 128K MOS ROMs, PROMs, and EPROMs.

The TMS27C128 EPROM is offered in a dual-in-line ceramic package (J suffix) designed for insertion in mounting hole rows on 15,2-mm (600-mil) centers. The TMS27C128 is offered with two operating temperature ranges of 0°C to 70°C (JL suffix) and -40°C to 85°C (JE suffix). The TMS27C128 is also offered with 168-hour burn-in temperature ranges (JL4 and JE4 suffixes). (See table below).

The TMS27PC128 PROM is offered in a dual-in-line plastic package (N suffix) designed for insertion in mounting hole rows on 15,2-mm (600-mil) centers. The TMS27PC128 is also supplied in a 32-lead plastic leaded chip carrier package using 1,25-mm (50-mil) lead spacing (FM suffix). The TMS27PC128 is also offered with two operating temperature ranges of 0°C to 70°C (NL and FML suffixes) and -40°C to 85°C (NE and FME suffixes). The TMS27PC128 is also offered with 168 hour burn-in temperature ranges (NL4, FML4, NE4, and FME4 suffixes). (See table below).

EPROM AND PROM	SUFFIX FOR TEMPERATU WITHOUT PE	RE RANGES	SUFFIX FOR OPERATING TEMPERATURE RANGES WITH PEP4 168 HR. BURN-IN		
	0°C TO 70°C	−40 °C TO 85°C	0 °C TO 85°C 0°C TO 70°C		
TMS27C128-XXX	JL	JE	JL4	JE4	
TMS27PC128-XXX	NL	NE	NL4	NE4	
TMS27PC128-XXX	FML	FME	FML4	FME4	

All package styles conform to JEDEC standards.

These EPROMs and PROMs operate from a single 5-V supply (in the read mode), thus are ideal for use in microprocessor-based systems. One other 12-13-V supply is needed for programming . All programming signals are TTL level. These devices are programmable by using the SNAP! Pulse programming algorithm. The SNAP! Pulse programming algorithm uses a V_{PP} of 13.0 V and a V_{CC} of 6.5 V for a nominal programming time of two seconds. For programming outside the system, existing EPROM programmers can be used. Locations may be programmed singly, in blocks, or at random.



SMLS128E-OCTOBER 1984-REVISED JANUARY 1993

operation

The seven modes of operation are listed in the following table. Read mode requires a single 5-V supply. All inputs are TTL level except for V_{PP} during programming (13 V for SNAP! Pulse), and 12 V on A9 for the signature mode.

				MODE	=			
FUNCTION	READ	OUTPUT DISABLE	STANDBY	PROGRAMMING	VERIFY	PROGRAM INHIBIT	SIGNA MO	-
E	VIL	VIL	VIH	VIL	VIL	VIH	V	L
G	VIL	VIH	X‡	VIH	VIL	Х	V	L
PGM	VIH	VIH	Х	VIL	VIH	Х	V	Н
VPP	VCC	VCC	VCC	VPP	VPP	VPP	٧c	C
V _{CC}	VCC	VCC	VCC	VCC	VCC	VCC	٧c	C
A9	Х	Х	Х	Х	Х	Х	VH	∨ _H ‡
A0	Х	Х	Х	Х	Х	Х	VIL	VIH
							CODE	
DQ0–DQ7	Data Out	HI-Z	HI-Z	Data In	Data Out	HI-Z	MFG	DEVICE
							97	83

[†]X can be VIL or VIH.

 $V_{\rm H} = 12 \ V \pm 0.5 \ V.$



SMLS128E-OCTOBER 1984-REVISED JANUARY 1993

read/output disable

When the outputs of two or more TMS27C128s or TMS27PC128s are connected in parallel on the same bus, the output of any particular device in the circuit can be read with no interference from the competing outputs of the other devices. To read the output of a single device, a low-level signal is applied to the \overline{E} and \overline{G} pins. All other devices in the circuit should have their outputs disabled by applying a high-level signal to one of these pins. Output data is accessed at pins DQ0 through DQ7.

latchup immunity

Latchup immunity on the TMS27C128 and TMS27PC128 is a minimum of 250 mA on all inputs and outputs. This feature provides latchup immunity beyond any potential transients at the P.C. board level when the devices are interfaced to industry-standard TTL or MOS logic devices. Input/output layout approach controls latchup without compromising performance or packing density.

power down

Active I_{CC} supply current can be reduced from 30 mA to 500 μ A (TTL-level inputs) or 250 μ A (CMOS-level inputs) by applying a high TTL or CMOS signal to the \overline{E} pin. In this mode all outputs are in the high-impedance state.

erasure (TMS27C128)

Before programming, the TMS27C128 EPROM is erased by exposing the chip through the transparent lid to a high intensity ultraviolet light (wavelength 2537 Å). EPROM erasure before programming is necessary to assure that all bits are at the logic high level. Logic lows are programmed into the desired locations. A programmed logic low can be erased only by ultraviolet light. The recommended minimum ultraviolet light exposure dose (UV intensity × exposure time) is 15-W·s/cm². A typical 12-mW/cm², filterless UV lamp will erase the device in 21 minutes. The lamp should be located about 2.5 cm above the chip during erasure. It should be noted that normal ambient light contains the correct wavelength for erasure. Therefore, when using the TMS27C128, the window should be covered with an opaque label.

initializing (TMS27PC128)

The one-time programmable TMS27PC128 PROM is provided with all bits at the logic high level. The logic lows are programmed into the desired locations. Logic lows programmed into a PROM cannot be erased.

SNAP! Pulse programming

The 128K EPROM and PROM are programmed using the TI SNAP! Pulse programming algorithm, illustrated by the flowchart in Figure 1, which programs in a nominal time of two seconds. Actual programming time will vary as a function of the programmer used.

Data is presented in parallel (eight bits) on pins DQ0 to DQ7. Once addresses and data are stable, PGM is pulsed.

The SNAP! Pulse programming algorithm uses initial pulses of 100 microseconds (μ s) followed by a byte verification to determine when the addressed byte has been successfully programmed. Up to 10 (ten) 100- μ s pulses per byte are provided before a failure is recognized.

The programming mode is achieved when $V_{PP} = 13$ V, $V_{CC} = 6.5$ V, $\overline{G} = V_{IH}$, and $\overline{E} = V_{IL}$. More than one device can be programmed when the devices are connected in parallel. Locations can be programmed in any order. When the SNAP! Pulse programming routine is complete, all bits are verified with $V_{CC} = V_{PP} = 5$ V.

program inhibit

Programming may be inhibited by maintaining a high level input on the \overline{E} or \overline{PGM} pin.



SMLS128E-OCTOBER 1984-REVISED JANUARY 1993

program verify

Programmed bits may be verified with $V_{PP} = 13 \text{ V}$ when $\overline{G} = V_{IL}$, $\overline{E} = V_{IL}$, and $\overline{PGM} = V_{IH}$.

signature mode

The signature mode provides access to a binary code identifying the manufacturer and type. This mode is activated when A9 is forced to 12 V \pm 0.5 V. Two identifier bytes are accessed by A0; i.e., A0 = V_{IL} accesses the manufacturer code, which is output on DQ0–DQ7; A0 = V_{IH} accesses the device code, which is output on DQ0–DQ7. All other addresses must be held at V_{IL}. The manufacturer code for these devices is 97, and the device code is 83.



SMLS128E-OCTOBER 1984-REVISED JANUARY 1993

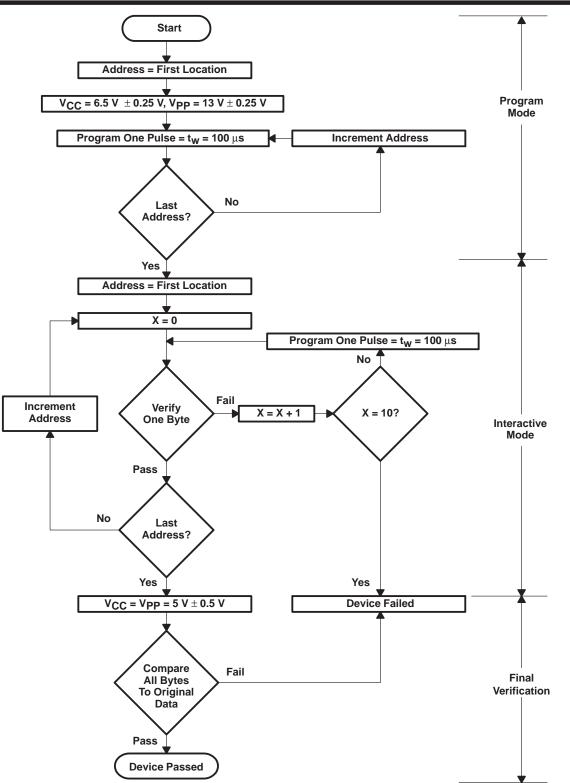
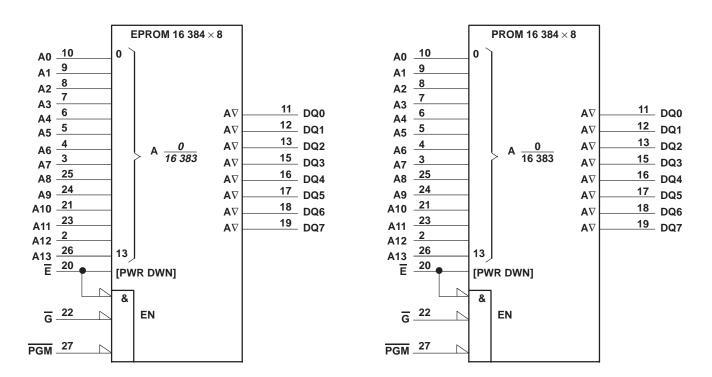


Figure 1. SNAP! Pulse Programming Flowchart



SMLS128E-OCTOBER 1984-REVISED JANUARY 1993

logic symbol[†]



[†] These symbols are in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12. Pin numbers shown are J and N packages.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[‡]

Supply voltage range, V _{CC} (see Note 1)	–0.6 V to 7 V
Supply voltage range, VPP (see Note 1)	
Input voltage range (see Note 1), All inputs except A9	\dots -0.6 V to V _{CC} + 1 V
A9	
Output voltage range (see Note 1)	\dots -0.6 V to V _{CC} + 1 V
Operating free-air temperature range ('27C128JL and JL4, '27PC128NL, ar	nd NL4
FML, and FML4)	0°C to 70°C
Operating free-air temperature range ('27C128JE and JE4, '27PC128NE, NI	Ξ4,
FME, and FME4)	−40°C to 85°C
Storage temperature range	−65°C to 150°C

[‡] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: Under absolute maximum ratings, voltage values are with respect to GND.



SMLS128E-OCTOBER 1984-REVISED JANUARY 1993

recommended operating conditions

				MIN	NOM	MAX	UNIT
Vee	Supply voltage	Read mode (se	e Note 2)	4.5	5	5.5	V
Vcc	Supply voltage	SNAP! Pulse pr	ogramming algorithm	6.25	6.5	6.75	v
Vaa	Supply voltage	Read mode		V _{CC} -0.6		V _{CC} + 0.6	V
VPP	Supply voltage	SNAP! Pulse pr	ogramming algorithm	12.75	13	13.25	v
	High lovel de input voltage		TTL	2		V _{CC} +1	V
VIH	IH High-level dc input voltage		CMOS	V _{CC} -0.2		V _{CC} +1	v
V	Low-level dc input voltage		TTL	-0.5		0.8	V
VIL	Low-level do input voltage		CMOS	-0.5		0.2	V
т _А	Q Operating free-air temperature		'27C128JL,JL4 '27PC128NL,NL4 FML, FML4	0		70	°C
Τ _Α	Operating free-air temperature		['] 27C128JE,JE4 '27PC128NE,NE4 FME, FME4	-40		70	°C

NOTES: 2. V_{CC} must be applied before or at the same time as V_{PP} and removed after or at the same time as V_{PP}. The device must not be inserted into or removed from the board when V_{PP} or V_{CC} is applied.

electrical characteristics over full ranges of operating conditions

	PARAMETER		TEST CONDITIONS	MIN	TYP†	MAX	UNIT
Valu	V _{OH} High-level dc output voltage		$I_{OH} = -2.5 \text{ mA}$	3.5			V
VОН			I _{OH} = -20 μA	V _{CC} -0.1			V
Vei	Low-level dc output voltage		I _{OL} = 2.1 mA			0.4	V
VOL	Low-level de output voltage		I _{OL} = 20 μA			0.1	V
Ц	Input current (leakage)		$V_{I} = 0$ to 5.5 V			±1	μA
IO	Output current (leakage)		$V_{O} = 0$ to V_{CC}			±1	μA
I _{PP1}	VPP supply current		$V_{PP} = V_{CC} = 5.5 V$		1	10	μA
IPP2	VPP supply current (during progra	am pulse)	Vpp = 13 V		35	50	mA
lasi		TTL-input level	$V_{CC} = 5.5 \text{ V}, \overline{\text{E}} = V_{IH}$		250	500	μA
ICC1	V _{CC} supply current (standby)	CMOS-input level	$V_{CC} = 5.5 V, \overline{E} = V_{CC}$		100	250	μΑ
ICC2	V _{CC} supply current (active)		$V_{CC} = 5.5 \text{ V}, \overline{E} = V_{IL},$ $t_{cycle} = \text{minimum cycle time,}$ outputs open		15	30	mA

[†] Typical values are at $T_A = 25^{\circ}C$ and nominal voltages.

capacitance over recommended ranges of supply voltage and operating free-air temperature, f = 1 MHz^{\ddagger}

	PARAMETER	TEST CONDITIONS	MIN	TYP [†]	MAX	UNIT
Ci	Input capacitance	V _I = 0, f = 1 MHz		6	10	pF
CO	Output capacitance	$V_{O} = 0, f = 1 MHz$		10	14	рF

[†] Typical values are at $T_A = 25^{\circ}C$ and nominal voltages.

Capacitance measurements are made on sample basis only.



SMLS128E-OCTOBER 1984-REVISED JANUARY 1993

switching characteristics over full ranges of recommended operating conditions (see Notes 3 and 4)

	PARAMETER	TEST CONDITIONS	'27C128-12		'27C/PC128-15		UNIT
	FARAMETER	(SEE NOTES 3 AND 4)	MIN	MAX	MIN	MAX	•••••
^t a(A)	Access time from address			120		150	ns
ta(E)	Access time from chip enable	C ₁ = 100 pF,		120		150	ns
ten(G)	Output enable time from G	1 Series 74 TTL Load,		55		75	ns
t _{dis}	Output disable time from \overline{G} or $\overline{E},$ whichever occurs first †	Input t _r ≤ 20 ns, Input t _f ≤ 20 ns	0	45	0	60	ns
t _{V(A)}	Output data valid time after change of address, \overline{E} , or \overline{G} , whichever occurs first [†]		0		0		ns

		TEST CONDITIONS	'27C/P0	C128-20	′27C/PC	2128-25	UNIT
		(SEE NOTES 3 AND 4)	MIN	MAX	MIN	MAX	•
ta(A)	Access time from address			200		250	ns
^t a(E)	Access time from chip enable	C _I = 100 pF,		200		250	ns
ten(G)	Output enable time from \overline{G}	1 Series 74 TTL Load,		75		100	ns
^t dis	Output disable time from $\overline{G}o$ r $\overline{E},$ whichever occurs first $\!\!\!\!^\dagger$	Input t _r ≤ 20 ns, Input t _f ≤ 20 ns	0	60	0	60	ns
t _{V(A)}	Output data valid time after change of address, $\overline{E},$ or $\overline{G},$ whichever occurs first †	input q 2 20 no	0		0		ns

[†] Value calculated from 0.5 V delta to measured level. This parameter is only sampled and not 100% tested.

switching characteristics for programming: $V_{CC} = 6.5$ V and $V_{PP} = 13$ V (SNAP! Pulse), $T_A = 25^{\circ}C$ (see Note 3)

	PARAMETER	MIN	NOM	MAX	UNIT
^t dis(G)	Output disable time from G	0		130	ns
ten(G)	Output enable time from G			150	ns

recommended timing requirements for programming: V_{CC} = 6.5 V and V_{PP} =13 V (SNAP! Pulse), T_A = 25°C (see Note 3)

			MIN	I NOM	MAX	UNIT
^t w(IPGM)	Initial program pulse duration	SNAP! Pulse programming algorithm	95	5 100	105	μs
^t su(A)	Address setup time			2		μs
^t su(E)	E setup time		2	2		μs
^t su(G)	G setup time		2	2		μs
^t su(D)	Data setup time		2	2		μs
tsu(VPP)	VPP setup time			2		μs
tsu(VCC)	V _{CC} setup time			2		μs
^t h(A)	Address hold time		()		μs
^t h(D)	Data hold time			2		μs

NOTES: 3. For all switching characteristics the input pulse levels are 0.4 V to 2.4 V. Timing measurements are made at 2 V for logic high and 0.8 V for logic low (reference page 10).

4. Common test conditions apply for tdis except during programming.



SMLS128E-OCTOBER 1984-REVISED JANUARY 1993

PARAMETER MEASUREMENT INFORMATION

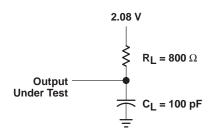
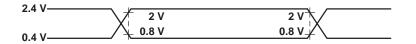
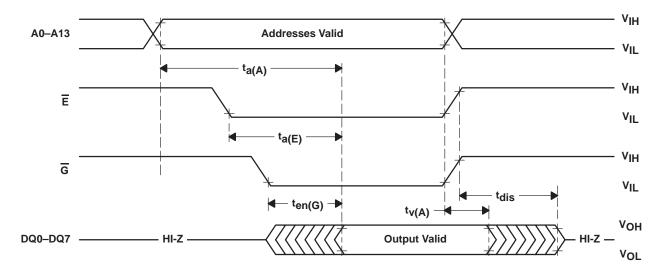


Figure 2. AC Testing Output Load Circuit

AC testing input/output wave forms



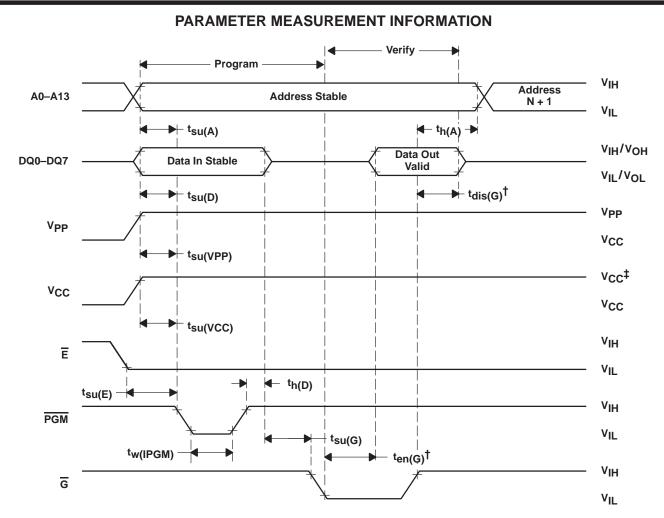
AC testing inputs are driven at 2.4 V for logic high and 0.4 V for logic low. Timing measurements are made at 2 V for logic high and 0.8 V for logic low for both inputs and outputs.







SMLS128E-OCTOBER 1984-REVISED JANUARY 1993



[†] $t_{dis(G)}$ and $t_{en(G)}$ are characteristics of the device but must be accommodated by the programmer. 13-V V_{PP} and 6.5-V V_{CC} for SNAP! Pulse programming.

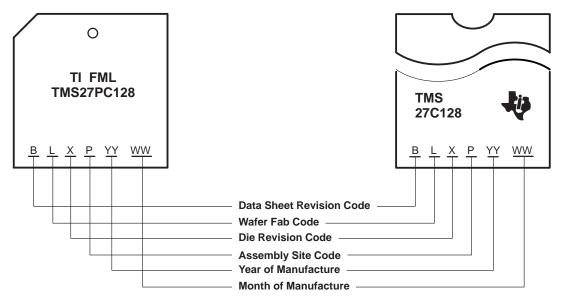
Figure 4. Program Cycle Timing



SMLS128E-OCTOBER 1984-REVISED JANUARY 1993

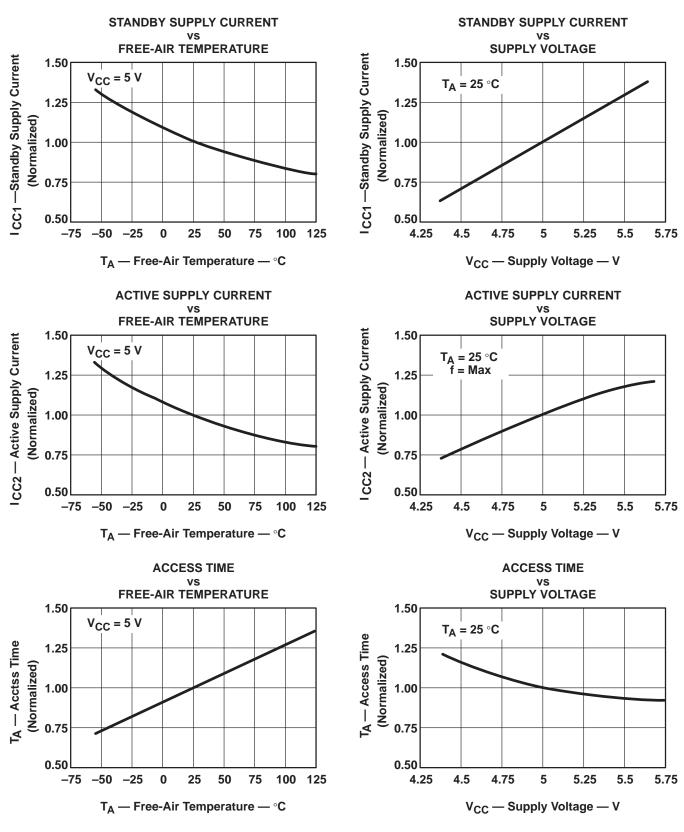
device symbolization

This data sheet is applicable to all TI TMS27C128 CMOS EPROMs and TMS27PC128 PROMs with the data sheet revision code "B" as shown below.





SMLS128E-OCTOBER 1984-REVISED JANUARY 1993



TYPICAL TMS27C/PC128 CHARACTERISTICS



IMPORTANT NOTICE

Texas Instruments and its subsidiaries (TI) reserve the right to make changes to their products or to discontinue any product or service without notice, and advise customers to obtain the latest version of relevant information to verify, before placing orders, that information being relied on is current and complete. All products are sold subject to the terms and conditions of sale supplied at the time of order acknowledgement, including those pertaining to warranty, patent infringement, and limitation of liability.

TI warrants performance of its semiconductor products to the specifications applicable at the time of sale in accordance with TI's standard warranty. Testing and other quality control techniques are utilized to the extent TI deems necessary to support this warranty. Specific testing of all parameters of each device is not necessarily performed, except those mandated by government requirements.

CERTAIN APPLICATIONS USING SEMICONDUCTOR PRODUCTS MAY INVOLVE POTENTIAL RISKS OF DEATH, PERSONAL INJURY, OR SEVERE PROPERTY OR ENVIRONMENTAL DAMAGE ("CRITICAL APPLICATIONS"). TI SEMICONDUCTOR PRODUCTS ARE NOT DESIGNED, AUTHORIZED, OR WARRANTED TO BE SUITABLE FOR USE IN LIFE-SUPPORT DEVICES OR SYSTEMS OR OTHER CRITICAL APPLICATIONS. INCLUSION OF TI PRODUCTS IN SUCH APPLICATIONS IS UNDERSTOOD TO BE FULLY AT THE CUSTOMER'S RISK.

In order to minimize risks associated with the customer's applications, adequate design and operating safeguards must be provided by the customer to minimize inherent or procedural hazards.

TI assumes no liability for applications assistance or customer product design. TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right of TI covering or relating to any combination, machine, or process in which such semiconductor products or services might be or are used. TI's publication of information regarding any third party's products or services does not constitute TI's approval, warranty or endorsement thereof.

Copyright © 1998, Texas Instruments Incorporated